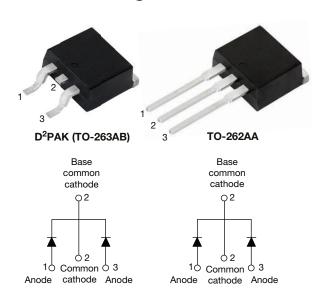


VS-40CTQ045S-M3

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Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 20 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 20 A					
V_R	45 V					
V _F at I _F	0.48 V					
I _{RM} max.	115 mA at 125 °C					
T _J max.	150 °C					
E _{AS}	20 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

VS-40CTQ045-1-M3

FEATURES

- 150 °C T_J operation
- Center tap configuration
- Very low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform	40	Α					
V _{RRM}		45	V					
I _{FSM}	t _p = 5 μs sine	1240	Α					
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.48	V					
T _J	Range	-55 to +150	°C					

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-40CTQ045S-M3 UNITS						
Maximum DC reverse voltage	V_{R}	45	V			
Maximum working peak reverse voltage	V_{RWM}	45	V			



VS-40CTQ045S-M3, VS-40CTQ045-1-M3

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER	ETER SYMBOL TEST CONDITIONS		VALUES	UNITS				
Maximum average	per leg				20			
forward current See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T _C = 116 °C	40	A			
Maximum peak one cycl	e non-repetitive		5 μs sine or 3 μs rect. pulse Following any rated load		1240			
surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse condition and with rated V _{RRM} applied		350			
Non-repetitive avalanche energy per leg		E _{AS}	$T_J = 25$ °C, $I_{AS} = 3$ A, $L = 4.40$ mH		20	mJ		
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	Α		

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST COI	TEST CONDITIONS				
		20 A	T _{.1} = 25 °C	0.53	V		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1 J = 25 C	0.68			
See fig. 1	V _{FM} (1)	20 A	T _{.1} = 125 °C	0.48			
		40 A	1j = 125 C	0.67			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V DetectV	3	A		
See fig. 2	IRM '''	T _J = 125 °C	V _R = Rated V _R	115	mA		
Threshold voltage	V _{F(TO)}	T T mayimum		0.27	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum		8.72	mΩ		
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range	2800	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 mm	8.0	nΗ			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHAN	THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	PARAMETER		TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storag temperature range	е	T _J , T _{Stg}		-55 to 150	°C			
Maximum thermal resistance, junction to case per leg		D	DC operation	2.0				
Maximum thermal resistance, junction to case per package		- R _{thJC}	DC Operation	1.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	minimum			6 (5)	kgf · cm			
Wounting torque	maximum			12 (10)	(lbf \cdot in)			
Marking device			Case style D ² PAK (TO-263AB)	40CTQ	045S			
			Case style TO-262AA	40CTQ045-1				



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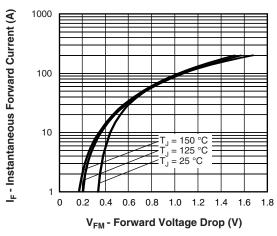


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

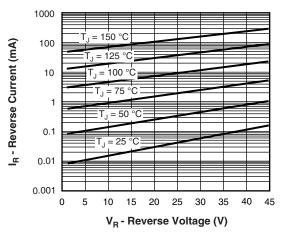


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

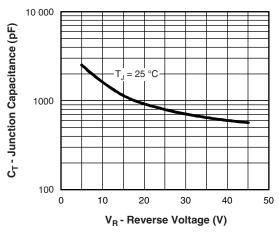


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

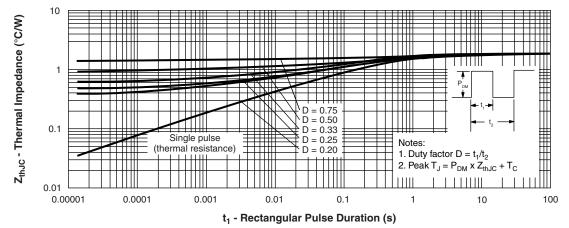


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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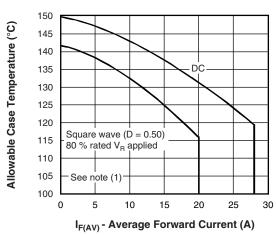


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

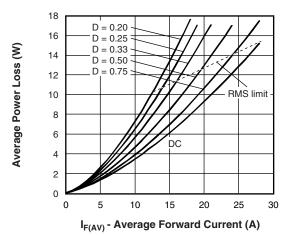


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

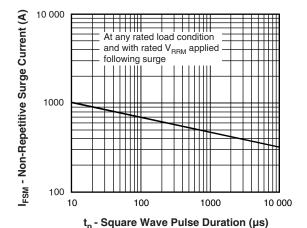


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

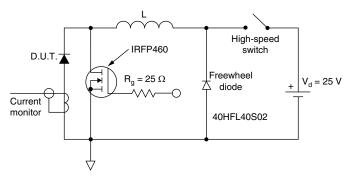


Fig. 8 - Unclamped Inductive Test Circuit

Note

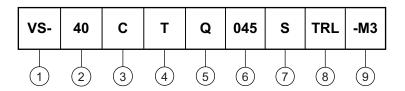
Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 10 V



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (40 A)

3 - Circuit configuration: C = common cathode

4 - T = TO-220

5 - Schottky "Q" series

6 - Voltage rating (045 = 45 V)

7 - • S = D^2PAK (TO-263AB)

• -1 = TO-262AA

8 - • None = tube

• TRL = tape and reel (left oriented - for D²PAK (TO-263AB) only)

• TRR = tape and reel (right oriented - for D²PAK (TO-263AB) only)

9 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-40CTQ045S-M3	50	1000	Antistatic plastic tubes					
VS-40CTQ045STRR-M3	800	800	13" diameter reel					
VS-40CTQ045STRL-M3	800	800	13" diameter reel					
VS-40CTQ045-1-M3	50	1000	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS					
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164			
Differsions	TO-262AA	www.vishay.com/doc?96165			
Dout moulding information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444			
Part marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		HES NOTES		OTES SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

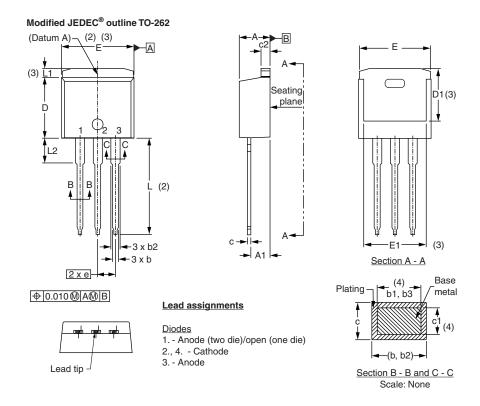
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	INCHES		
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.10	D BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.36	3.71	0.132	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- 5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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